

PNP -2.5A -80V Middle Power Transistor

Parameter	Value
V_{CEO}	-80V
I _C	-2.5A

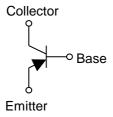
Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR544P
- 3) Low V_{CE(sat)}

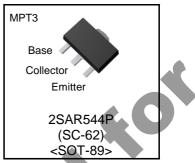
$$V_{CE(sat)} = -0.4V \text{ Max. } (I_C/I_B = -1A/-50\text{mA})$$

4) Lead Free/RoHS Compliant.

•Inner circuit



Outline



Applications

Motor driver, LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR544P	MPT3	4540	T100	180	12	1,000	MS

● Absolute maximum ratings (Ta = 25°C)

Parame	eter	Symbol	Values	Unit
Collector-base voltage		V_{CBO}	-80	V
Collector-emitter voltage		V_{CEO}	-80	V
Emitter-base voltage		V _{EBO}	-6	V
Collector current	DC	I _C	-2.5	А
	Pulsed	I _{CP} *1	-5.0	А
Power dissipation	2SAR544P	P_{D}	0.5 ^{*2}	W
- wei dissipation	20/11/0441	י ט	2.0 *3	W
Junction temperature		T_j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

^{*1} Pw=10ms, single pulse *2 Each terminal mounted on a reference land

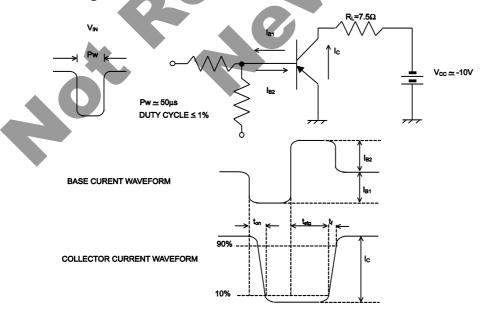
^{*3} Mounted on a ceramic board (40×40×.70mm)

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	$I_C = -1mA$	-80	-	-	V
Collector-base breakdown voltage	BV _{CBO}	$I_C = -100 \mu A$	-80	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	$I_E = -100 \mu A$	-6	ı		V
Collector cut-off current	I _{CBO}	$V_{CB} = -80V$	ı	-	1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = -4V$	-	-	-1	μΑ
Collector-emitter saturation voltage	V _{CE(sat)} *1	$I_{\rm C} = -1A, \ I_{\rm B} = -50 {\rm mA}$		-0.20	-0.40	V
DC current gain	h _{FE}	$V_{CE} = -3V, I_{C} = -100 \text{mA}$	120	-	390	-
Transition frequency	f _T	$V_{CE} = -10V, I_{E} = 500\text{mA}$ f=100MH _Z	_	280	-	MHz
Output capacitance	C _{ob}	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz		32	-	pF
Turn-on time	t _{on} *2	I _C = −1.3A	Ĵ	50	ı	ns
Storage time	t _{stg} *2	I _{B1} = -130mA I _{B2} =130mA	-	400	-	ns
Fall time	t _f *2	V _{CC} [≃] −10V	-	40	-	ns

^{*1} Pulsed

•Switching time test circuit



^{*2} See switching time test circuit

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

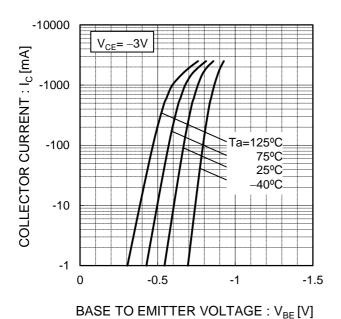
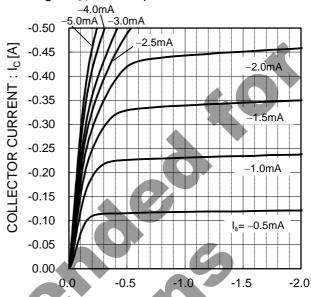


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE}[V]

Fig.3 DC Current Gain vs. Collector Current(I)

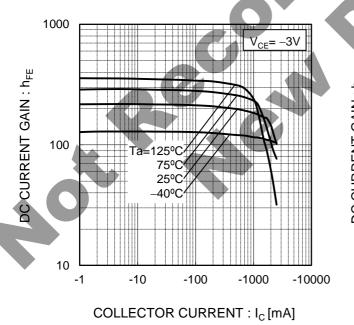
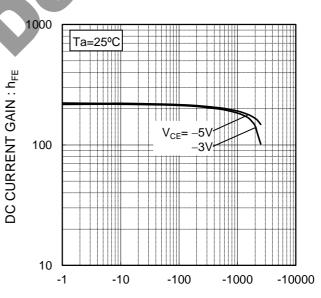


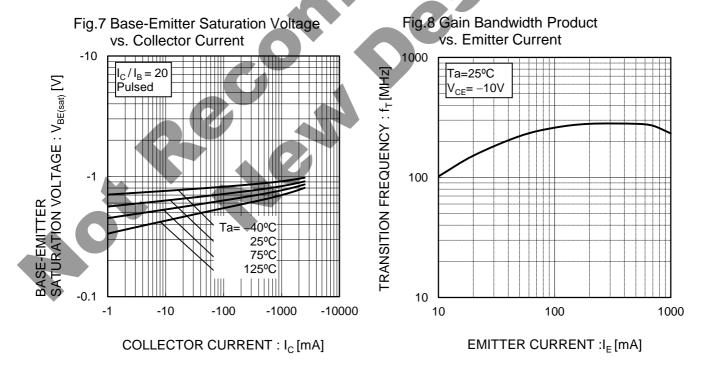
Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I_C [mA]

●Electrical characteristic curves(Ta = 25°C)

Fig.6 Collector-Emitter Saturation Voltage Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II) vs. Collector Current (I) -1 $I_{\rm C}/I_{\rm B} = 20$ Ta=25°C COLLECTOR-EMITTER SATURATION VOLTAGE : V_{CE(sat)} [V] SATURATION VOLTAGE: V_{CE(sat)} [V] COLLECTOR-EMITTER -0.1 -0.1 $I_{\rm C}/I_{\rm B} = 50^{\circ}$ 20 Ta=125°C 10 75°C 25°C -40°C -0.01 -1 -100 -1000 -10000 -100 -1000 -10000 COLLECTOR CURRENT : I_C [mA] COLLECTOR CURRENT : I_C [mA]



●Electrical characteristic curves(Ta = 25°C)

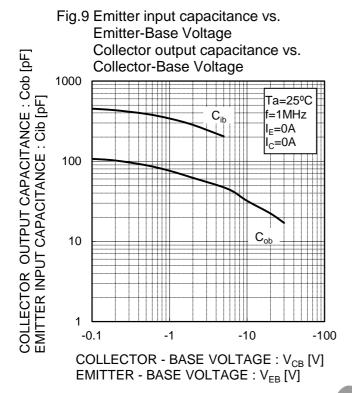
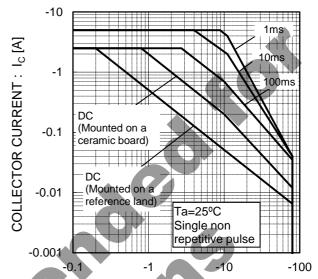
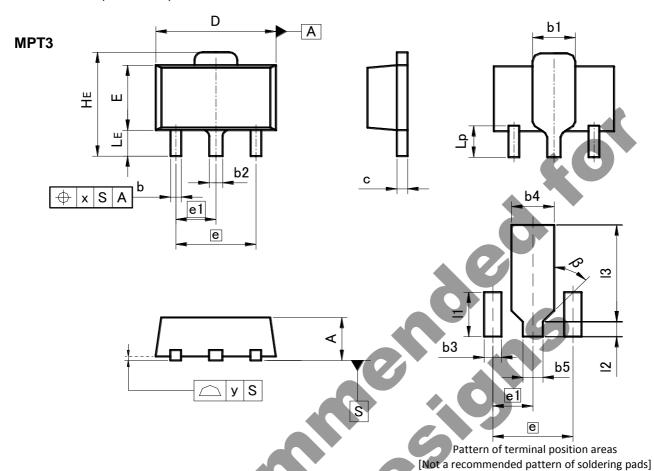


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : V_{CE} [V]

● **Dimensions** (Unit: mm)



		·			
DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
G	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.1	18	
e1	1.	50	0.0	59	
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
X	_	0.15	_	0.006	
У	-	0.10	-	0.004	

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b3	_	0.65	I	0.026
b4	-	1.70	1	0.067
b5	_	0.75	-	0.030
l1		1.71	I	0.067
12	_	0.58	I	0.023
13	_	3.72	_	0.146
β	45°		45°	

Dimension in mm / inches

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